

Surface Mount General Purpose Silicon Rectifiers

Reverse Voltage -50 to 1000V

Forward Current -2A

FEATURES

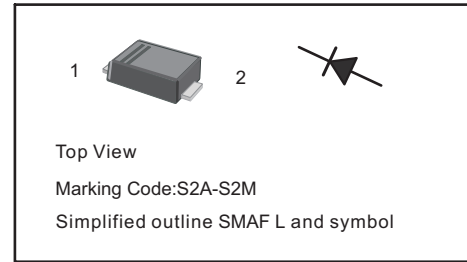
- For surface mounted applications
- Low profile package
- Glass Passivated Chip Junction
- Easy to pick and place
- Lead free in comply with EU RoHS 2011/65/EU directives

MECHANICAL DATA

- Case: SMAF
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 27mg 0.00086oz

PINNING

| PIN | DESCRIPTION |
|-----|-------------|
| 1 | Cathode |
| 2 | Anode |



Maximum Ratings and Electrical characteristics

Ratings at 25°C ambient temperature unless otherwise specified. Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

| Parameter | Symbols | S2AF | S2BF | S2DF | S2GF | S2JF | S2KF | S2MF | Units |
|--|-----------------|------------|------|------|------|------|------|------|--------------------|
| Maximum Repetitive Peak Reverse Voltage | V_{RRM} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Maximum RMS voltage | V_{RMS} | 35 | 70 | 140 | 280 | 420 | 560 | 700 | V |
| Maximum DC Blocking Voltage | V_{DC} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Maximum Average Forward Rectified Current at $T_a = 65^\circ\text{C}$ | $I_{F(AV)}$ | 2 | | | | | | | A |
| Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method) | I_{FSM} | 60 | | | | | | | A |
| Maximum Instantaneous Forward Voltage at 2 A | V_F | 1.1 | | | | | | | V |
| Maximum DC Reverse Current at Rated DC Blocking Voltage $T_a = 25^\circ\text{C}$ $T_a = 125^\circ\text{C}$ | I_R | 5 50 | | | | | | | μA |
| Typical Junction Capacitance ¹⁾ | C_j | 30 | | | | | | | pF |
| Typical Thermal Resistance ²⁾ | $R_{\theta JA}$ | 50 | | | | | | | $^\circ\text{C/W}$ |
| Operating and Storage Temperature Range | T_j, T_{stg} | -55 ~ +150 | | | | | | | $^\circ\text{C}$ |

1) Measured at 1 MHz and applied reverse voltage of 4 V D.C

2) Thermal resistance from junction to ambient at 0.375" (9.5 mm) lead length, P.C.B. mounted

Fig.1 Forward Current Derating Curve

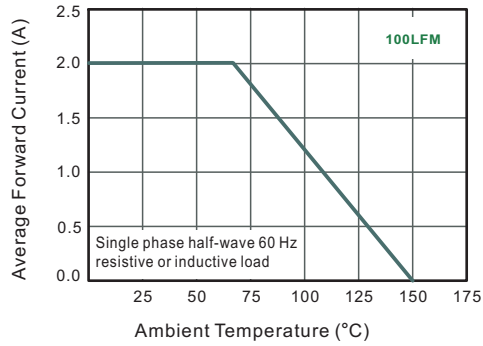


Fig.2 Typical Instantaneous Reverse Characteristics

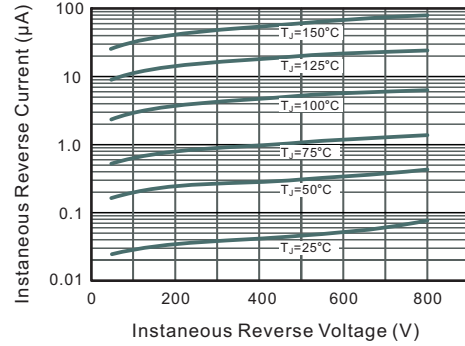


Fig.3 Typical Forward Characteristic

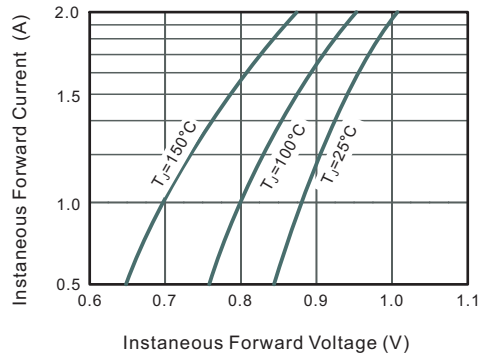
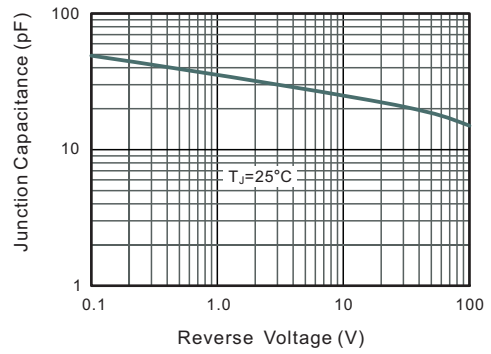


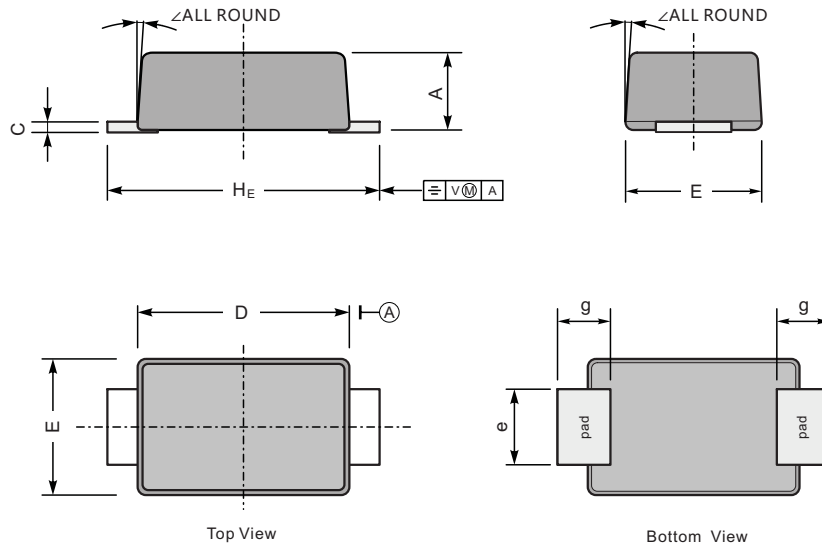
Fig.4 Typical Junction Capacitance



PACKAGE OUTLINE

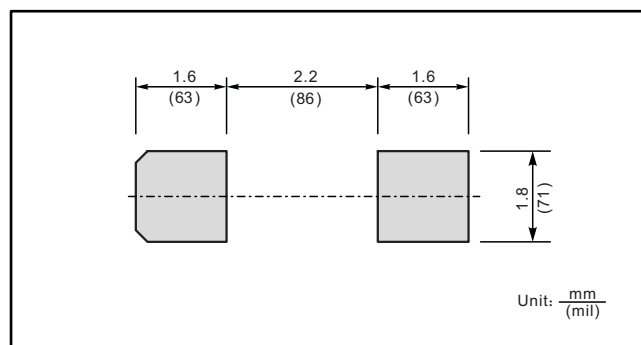
Plastic surface mounted package; 2 leads

SMAF



| UNIT | | A | C | D | E | e | g | H _E | ∠ |
|------|-----|-----|------|-----|-----|-----|-----|----------------|----|
| mm | max | 1.1 | 0.20 | 3.7 | 2.7 | 1.6 | 1.2 | 4.9 | 7° |
| | min | 0.9 | 0.12 | 3.3 | 2.4 | 1.3 | 0.8 | 4.4 | |
| mil | max | 43 | 7.9 | 146 | 106 | 63 | 47 | 193 | |
| | min | 35 | 4.7 | 130 | 94 | 51 | 31 | 173 | |

The recommended mounting pad size



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